

The Measurement of (1/f) AM noise of Oscillators

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Outline

- * Introduction
- * Power detectors
- * Experimental method
- * Results
- * Perspectives and conclusions

Motivations for AM noise metrology

- Emerging need, after the progress of
 - oscillators and sources
 - phase noise metrology (bridge/interferometric) method
- Impacts on
 - frequency synthesis \Leftrightarrow AM/PM conversion
 - oscillators \Leftrightarrow power effects on the resonator
 - microwave photonic systems \Leftrightarrow laser RIN
 -
- Measurement the AM noise of a *source* relies on instruments

AM noise

polar coordinates

$$v(t) = V_0 [1 + \alpha(t)] \cos [\omega_0 t + \varphi(t)]$$

Cartesian coordinates

$$v(t) = V_0 \cos \omega_0 t + n_c(t) \cos \omega_0 t - n_s(t) \sin \omega_0 t$$

In low noise conditions

$$\alpha(t) = \frac{n_c(t)}{V_0} \quad \text{and} \quad \varphi(t) = \frac{n_s(t)}{V_0}$$

Relates to power fluctuations

$$\alpha(t) = \frac{1}{2} \frac{\delta P}{P_0}$$

Same formulae as for frequency noise

$$\alpha(t) \Leftrightarrow y(t)$$

Power-law

$$S_\alpha(f) = \sum_{i=-2}^0 h_i f^i$$

h_{-2}/f^2 random walk
 h_{-1}/f flicker
 h_0 white

Allan variance

$$\sigma_\alpha^2(\tau) = \frac{h_0}{2\tau} + 2 \ln(2) h_{-1} + \frac{4\pi^2}{6} h_{-2} \tau$$

white

flicker

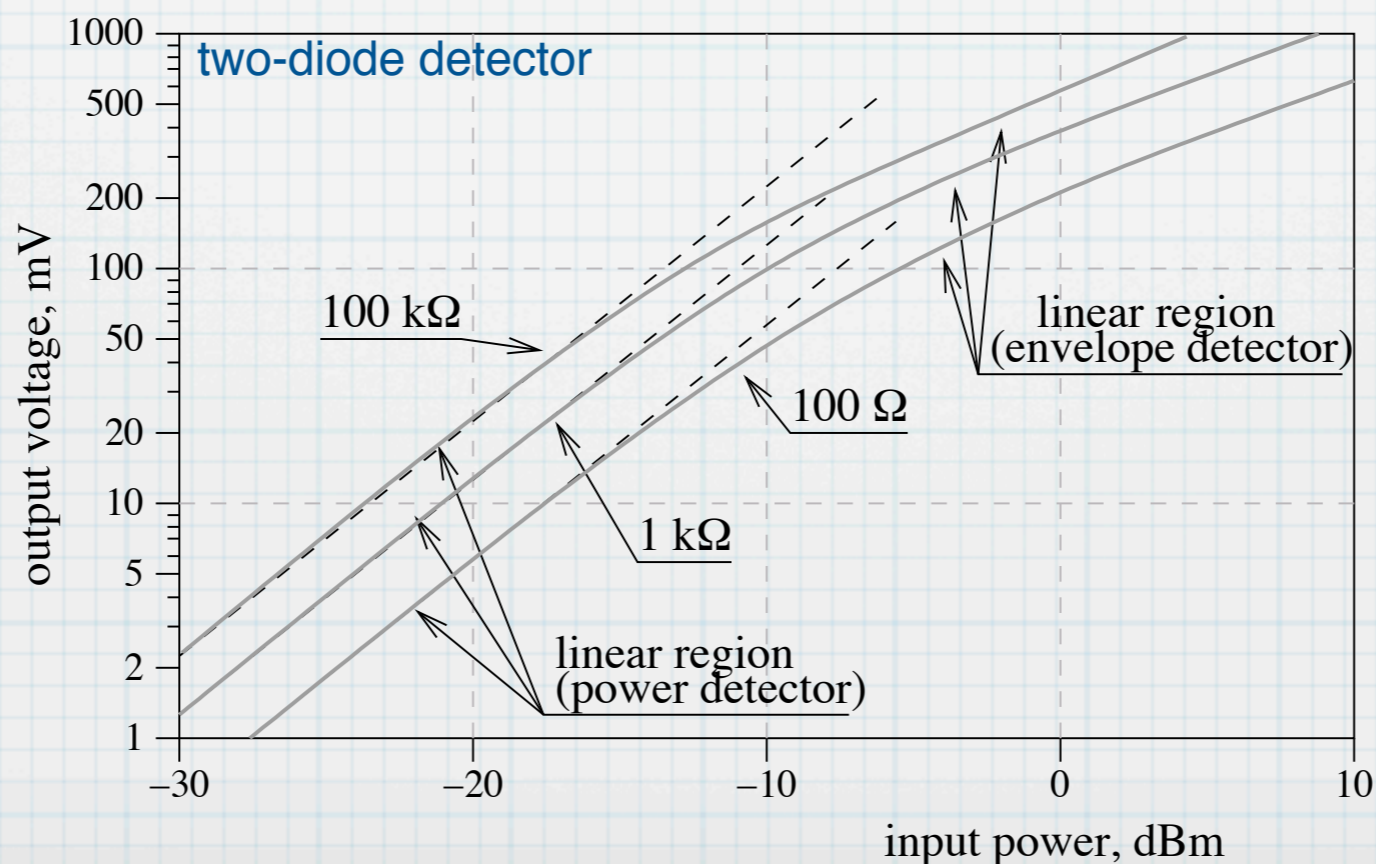
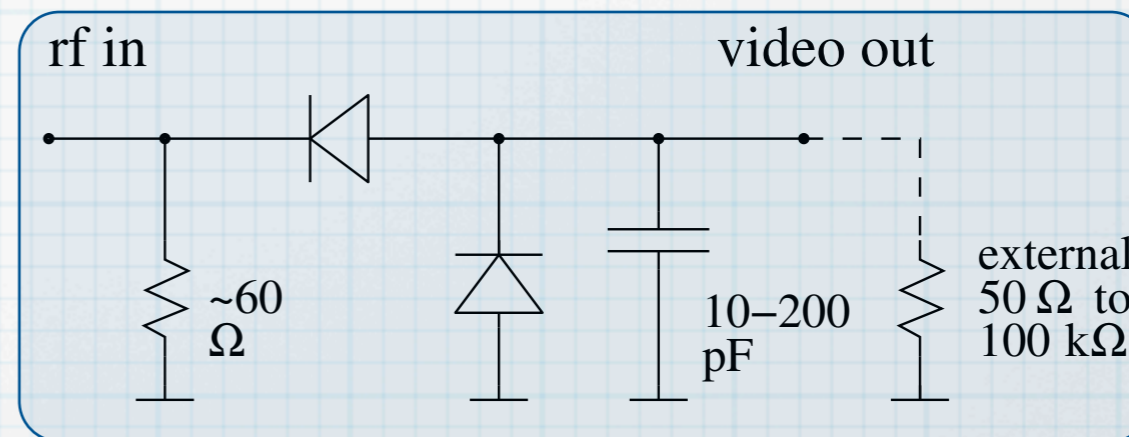
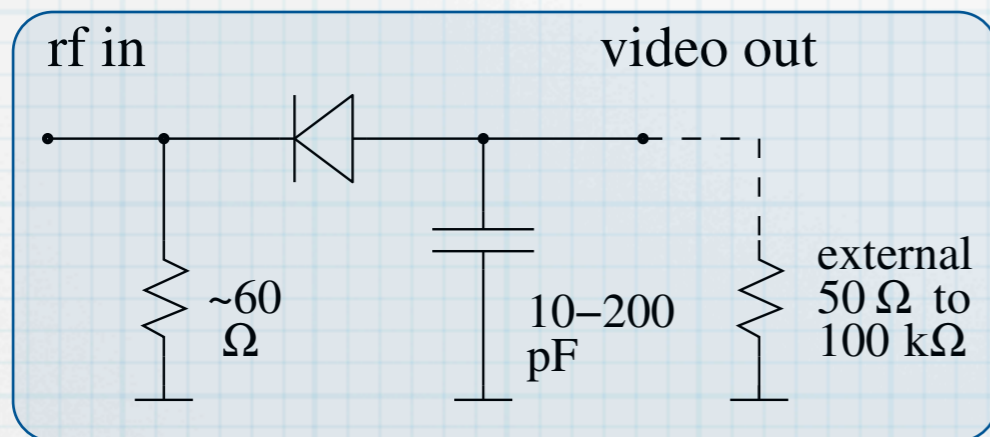
random walk

The diode power detector

law: $v = k_d P$

same form as in optical quantum detectors

differential resistance $R_d = \frac{V_T}{I_0}$ $V_T = kT/q \simeq 25 \text{ mV}$ thermal voltage



Tunnel and Schottky power detectors

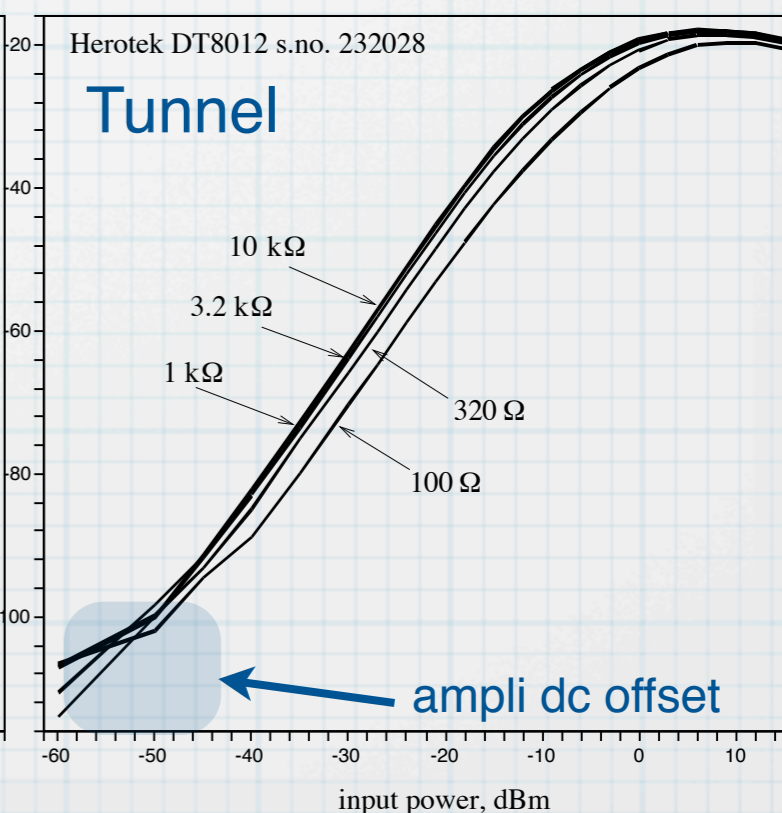
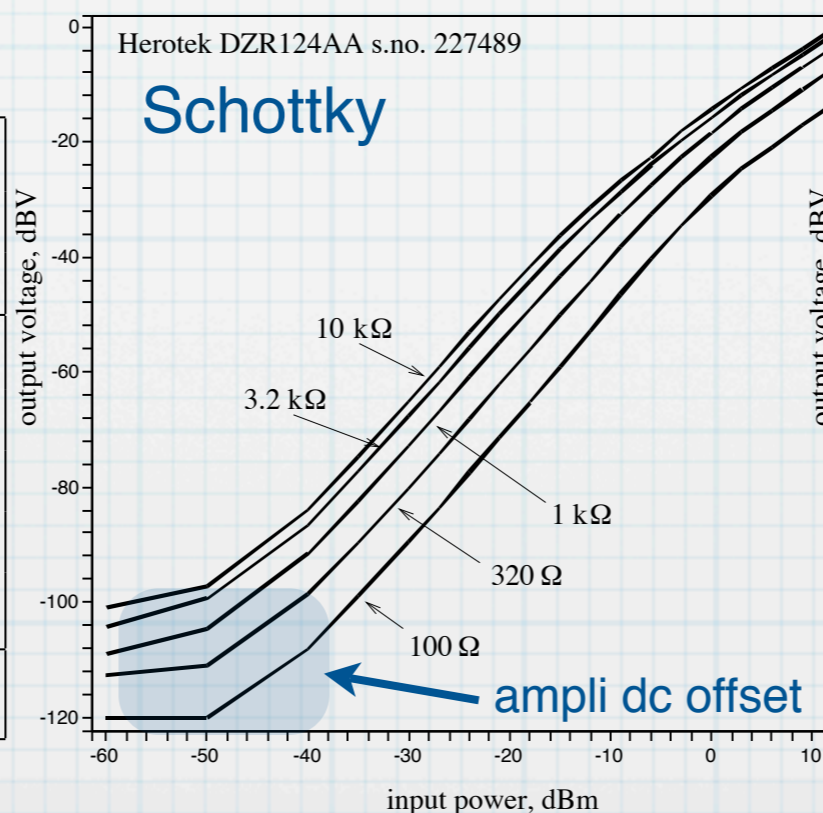
parameter	Schottky	tunnel
input bandwidth	up to 4 decades 10 MHz to 20 GHz	1–3 octaves up to 40 GHz
VSVR max.	1.5:1	3.5:1
max. input power (spec.)	–15 dBm	–15 dBm
absolute max. input power	20 dBm or more	20 dBm
output resistance	1–10 kΩ	50–200 Ω
output capacitance	20–200 pF	10–50 pF
gain	300 V/W	1000 V/W
cryogenic temperature	no	yes
electrically fragile	no	yes

The “tunnel” diode is actually a backward diode. The negative resistance region is absent.

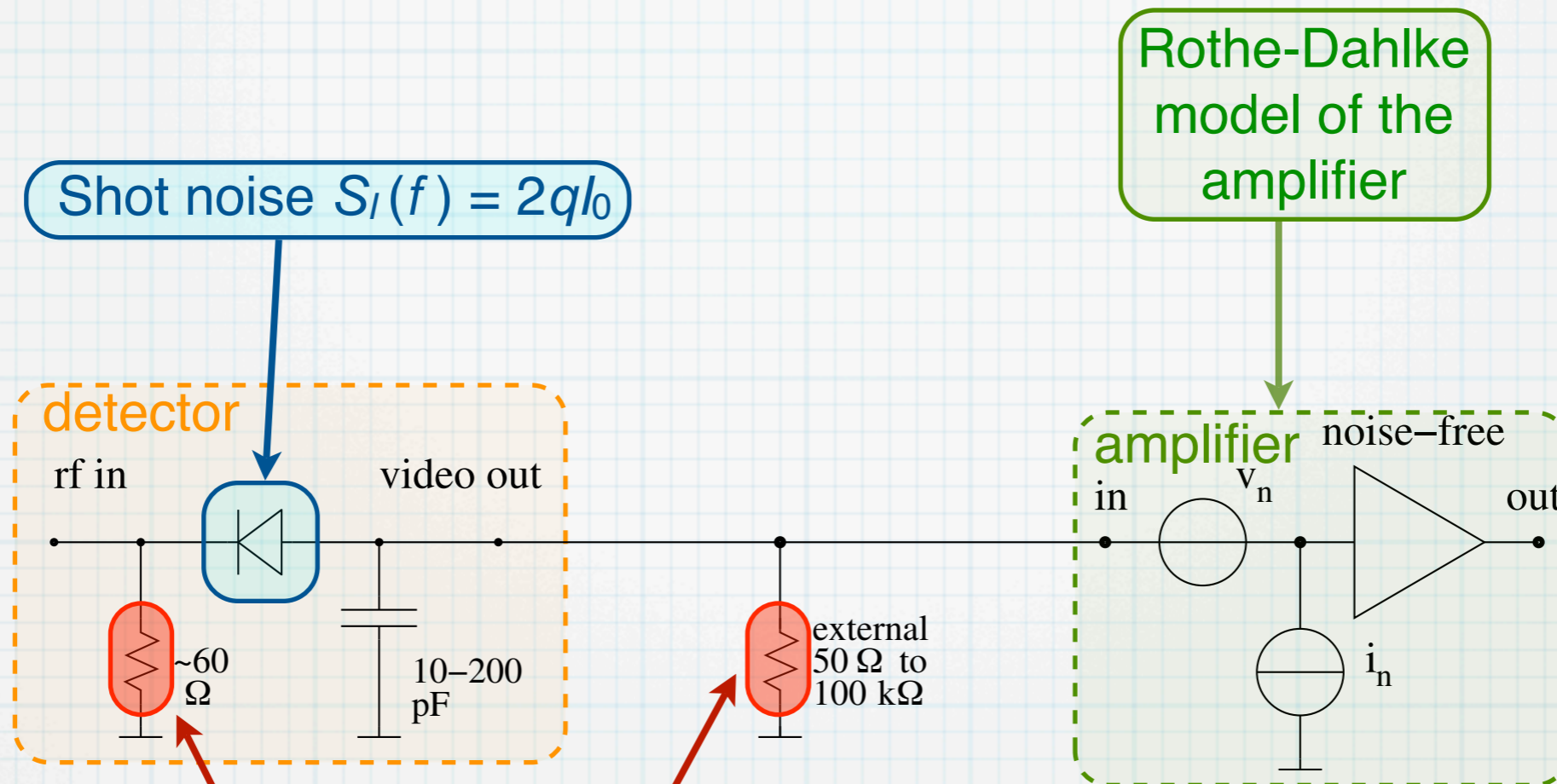
Measured

load resistance, Ω	detector gain, A ⁻¹	
	DZR124AA (Schottky)	DT8012 (tunnel)
1 × 10 ²	35	292
3.2 × 10 ²	98	505
1 × 10 ³	217	652
3.2 × 10 ³	374	724
1 × 10 ⁴	494	750

conditions: power –50 to –20 dBm



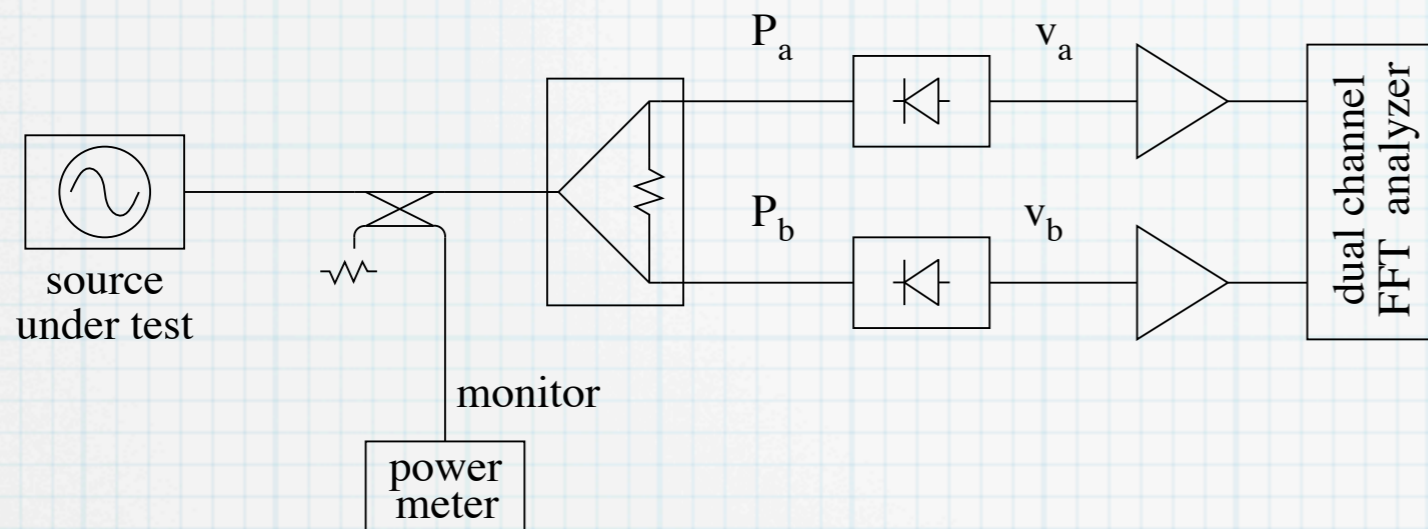
Noise mechanisms



In practice

the amplifier white noise turns out to be higher than the detector noise
and the amplifier flicker noise is even higher

Cross-spectrum method

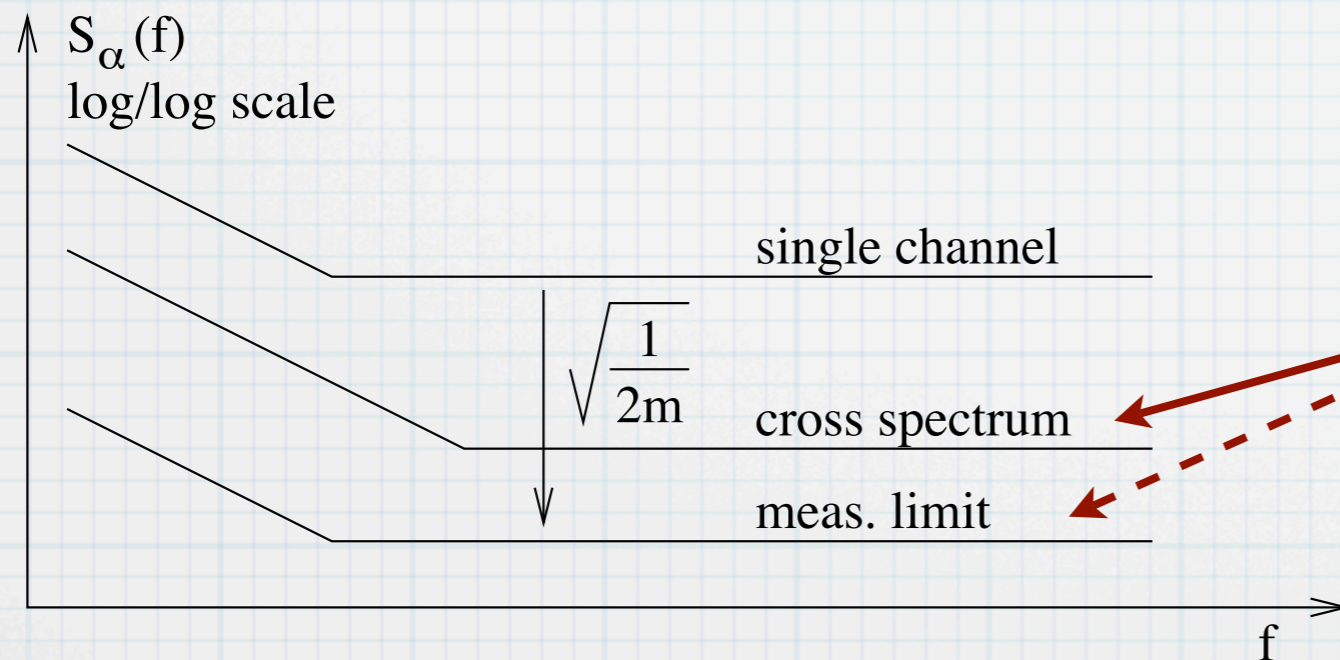


$$v_a(t) = 2k_a P_a \alpha(t) + \text{noise}$$

$$v_b(t) = 2k_b P_b \alpha(t) + \text{noise}$$

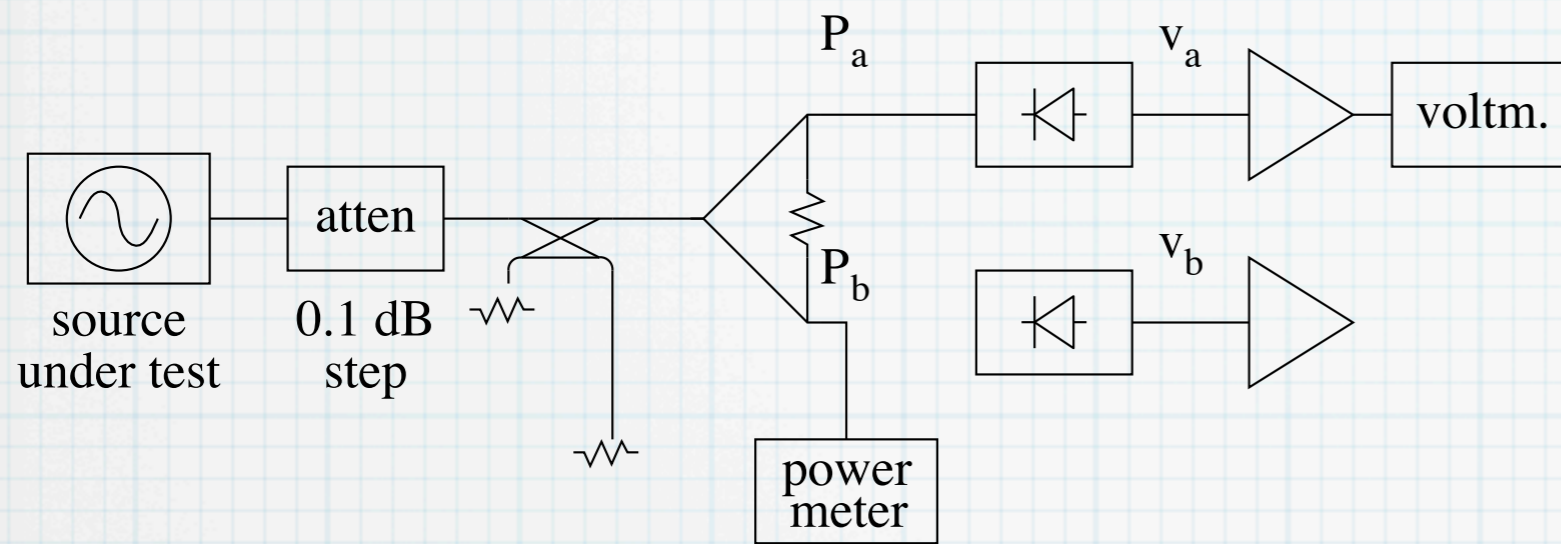
The cross spectrum $S_{ba}(f)$ rejects the single-channel noise because the two channels are independent.

$$S_{ba}(f) = \frac{1}{4k_a k_b P_a P_b} S_\alpha(f)$$



- Averaging on m spectra, the single-channel noise is rejected by $\sqrt{1/2m}$
- A cross-spectrum higher than the averaging limit validates the measure
- The knowledge of the single-channel noise is not necessary

Calibration



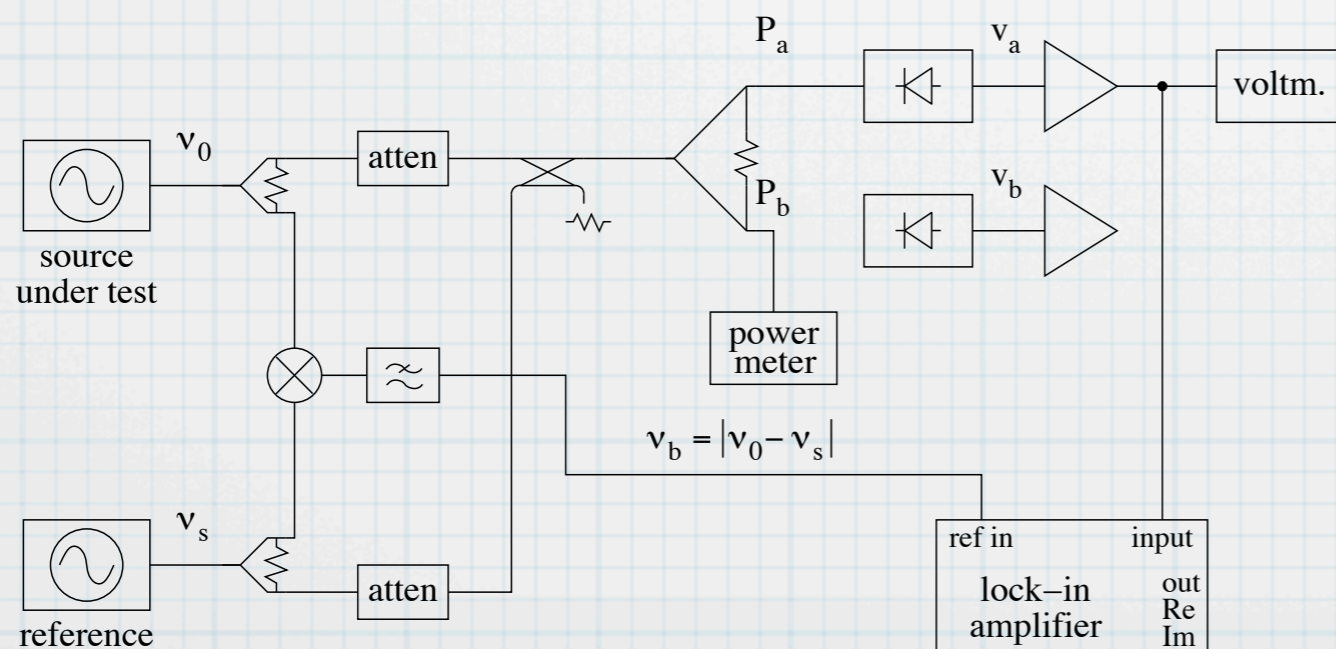
- Set a reference $\Delta P/P_a$ (0.1 dB) with a by-step attenuator
- Measure Δv_a at the output

$$k_a P_a = \frac{\Delta v_a}{\Delta P/P_a}$$

- Repeat interchanging the channels

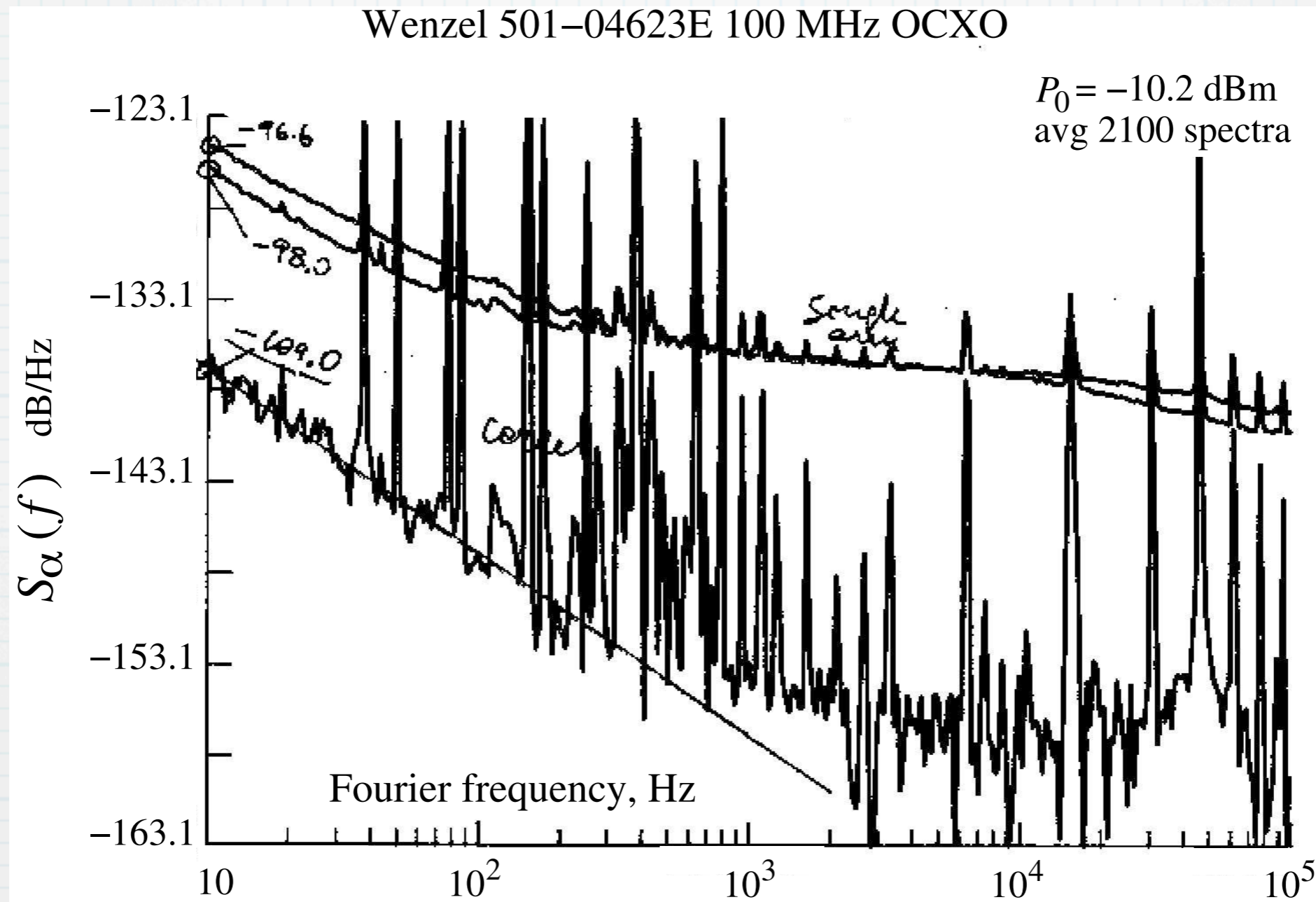
Note that only the kP product is needed because

$$S_{ba}(f) = \frac{1}{4k_a k_b P_a P_b} S_{\alpha}(f)$$



- Alternate (and complex) calibration method.
- It exploits the sensitivity and the accuracy of a lock-in amplifier.
 - As before, it requires a reference power-ratio

Example of AM noise spectrum



flicker: $h_{-1} = 1.5 \times 10^{-13} \text{ Hz}^{-1}$ (-128.2 dB) $\Rightarrow \sigma_\alpha = 4.6 \times 10^{-7}$

Single-arm 1/f noise is that of the dc amplifier
(the amplifier is still not optimized)

AM noise of some sources

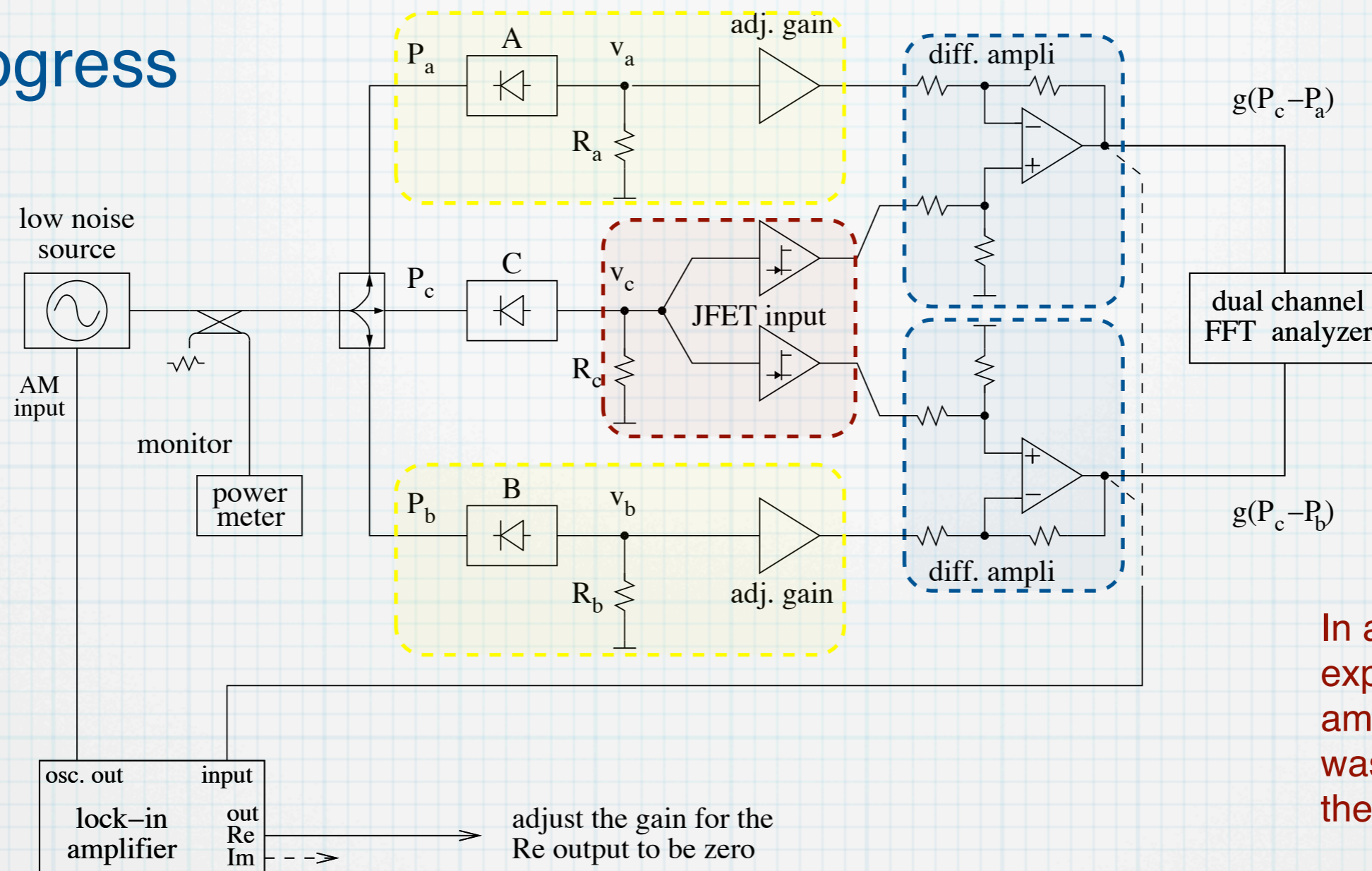
source	h_{-1} (flicker)		$(\sigma_\alpha)_{\text{floor}}$
Anritsu MG3690A synthesizer (10 GHz)	2.5×10^{-11}	-106.0 dB	5.9×10^{-6}
Marconi synthesizer (5 GHz)	1.1×10^{-12}	-119.6 dB	1.2×10^{-6}
Macom PLX 32-18 0.1 → 9.9 GHz multipl.	1.0×10^{-12}	-120.0 dB	1.2×10^{-6}
Omega DRV9R192-105F 9.2 GHz DRO	8.1×10^{-11}	-100.9 dB	1.1×10^{-5}
Narda DBP-0812N733 amplifier (9.9 GHz)	2.9×10^{-11}	-105.4 dB	6.3×10^{-6}
HP 8662A no. 1 synthesizer (100 MHz)	6.8×10^{-13}	-121.7 dB	9.7×10^{-7}
HP 8662A no. 2 synthesizer (100 MHz)	1.3×10^{-12}	-118.8 dB	1.4×10^{-6}
Fluke 6160B synthesizer	1.5×10^{-12}	-118.3 dB	1.5×10^{-6}
Racal Dana 9087B synthesizer (100 MHz)	8.4×10^{-12}	-110.8 dB	3.4×10^{-6}
Wenzel 500-02789D 100 MHz OCXO	4.7×10^{-12}	-113.3 dB	2.6×10^{-6}
Wenzel 501-04623E no. 1 100 MHz OCXO	2.0×10^{-13}	-127.1 dB	5.2×10^{-7}
Wenzel 501-04623E no. 2 100 MHz OCXO	1.5×10^{-13}	-128.2 dB	4.6×10^{-7}

worst

best

Measurement of the detector noise

In progress



In all previous experiments, the amplifier noise was higher than the detector noise

Basic ideas

- Remove the noise of the source by balancing C–A and C–B
 - Use a lock-in amplifier to get a sharp null measurement
- Channels A and B are independent → noise is averaged out
- Two separate JFET amplifiers are needed in the C channel
 - JFETs have virtually no bias-current noise
- **Only the noise of the detector C remains**

Conclusions

- * **Method for the measurement of AM noise in oscillators**
 - * **High sensitivity and accurate calibration**
 - * **Suitable to optics and to microwave photonics**
 - * **Measurement of some RF/microwave sources**
- * **Single-channel sensitivity still limited by the dc amplifier**
- * **Measurement of the detector noise in progress**

<http://rubiola.org>

Free downloads (text and slides)

<http://arxiv.org/abs/physics/0512082> (text only)